

L Number	Hits	Search Text	DB	Time stamp
1	775006	semiconductor	USPAT; US-PGPUB; EPO; JPO	2004/03/12 12:43
2	520	semiconductor and(sacrificial disposable expandable temporary) same (bottom base lower) near7 (opening\$1 groove\$1 trench\$2 hole\$1 aperture\$1)same substrate	USPAT; US-PGPUB; EPO; JPO	2004/03/12 12:46
3	245	(semiconductor and(sacrificial disposable expandable temporary) same (bottom base lower) near7 (opening\$1 groove\$1 trench\$2 hole\$1 aperture\$1)same substrate	USPAT; US-PGPUB; EPO; JPO	2004/03/12 12:46
4	88	and etch\$3 near3 (stop\$4 inhibit\$3 prevent\$3 resist\$3) ((semiconductor and(sacrificial disposable expandable temporary) same (bottom base lower) near7 (opening\$1 groove\$1 trench\$2 hole\$1 aperture\$1)same substrate) and etch\$3 near3 (stop\$4 inhibit\$3 prevent\$3 resist\$3)) and (protect\$3 prevent\$3 inhibit\$3) near10 (bottom base lower)	USPAT; US-PGPUB; EPO; JPO	2004/03/12 12:48